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Thermal characteristics

2 Thermal characteristics

Table 3 Thermal resistance

Parameter	Symbol	Values			Unit	Note or test condition
		Min.	Typ.	Max.		
Junction - soldering point	R_{thJS}	–	240	–	K/W	–

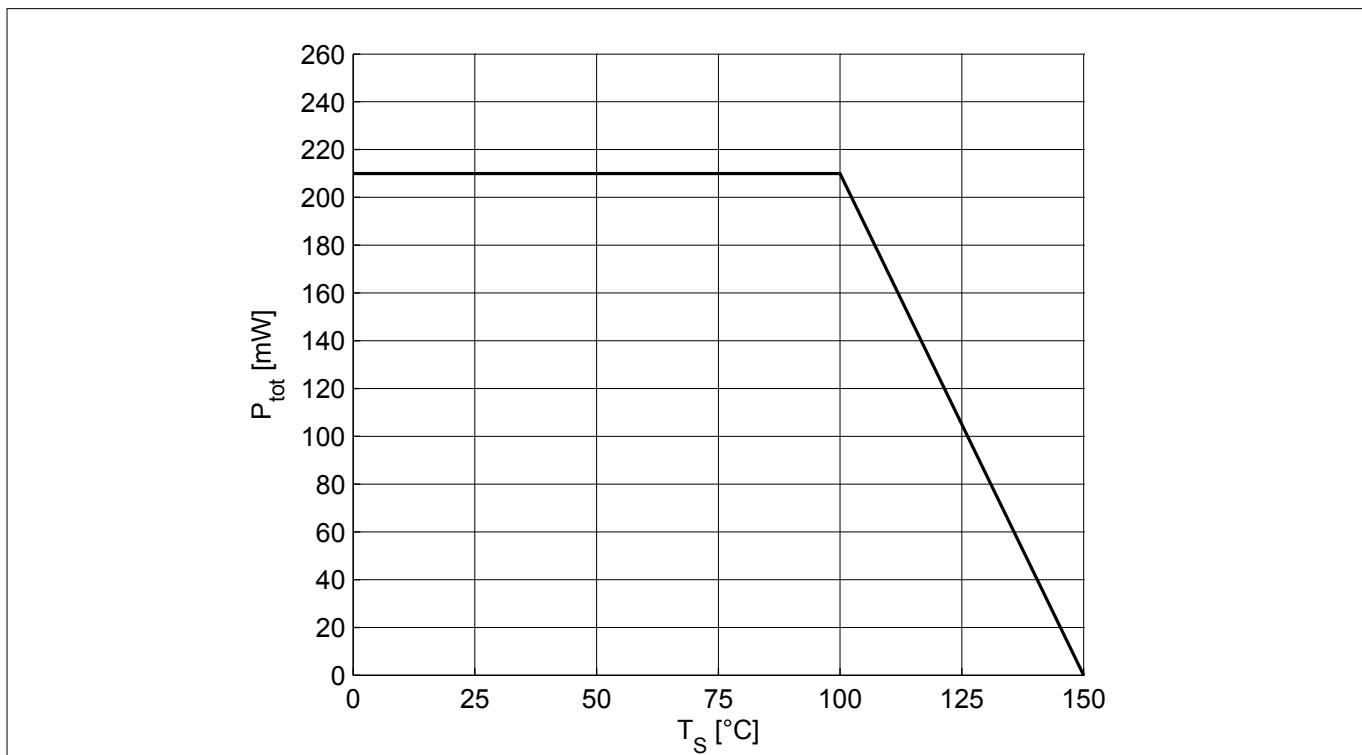


Figure 1 Total power dissipation $P_{\text{tot}} = f(T_S)$

Electrical characteristics

3.4

Characteristic DC diagrams

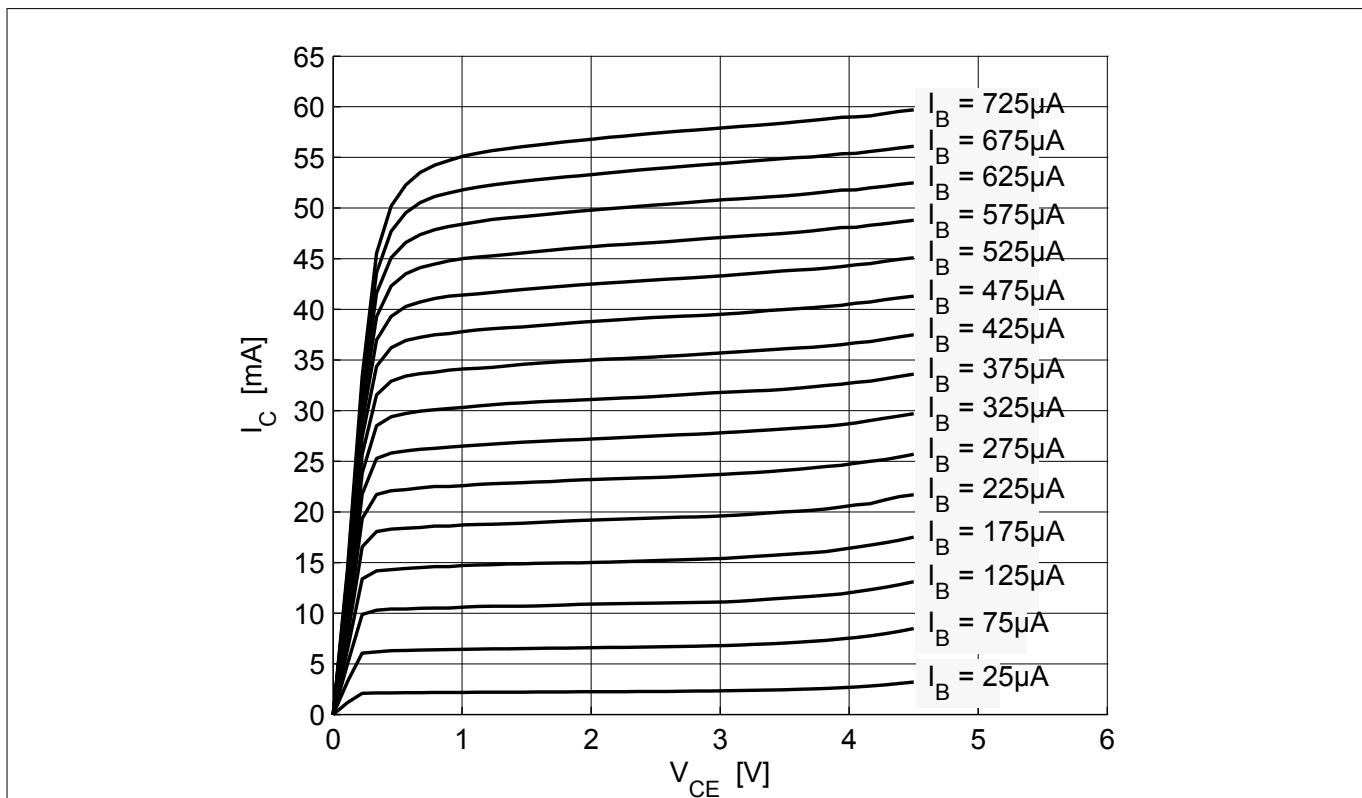
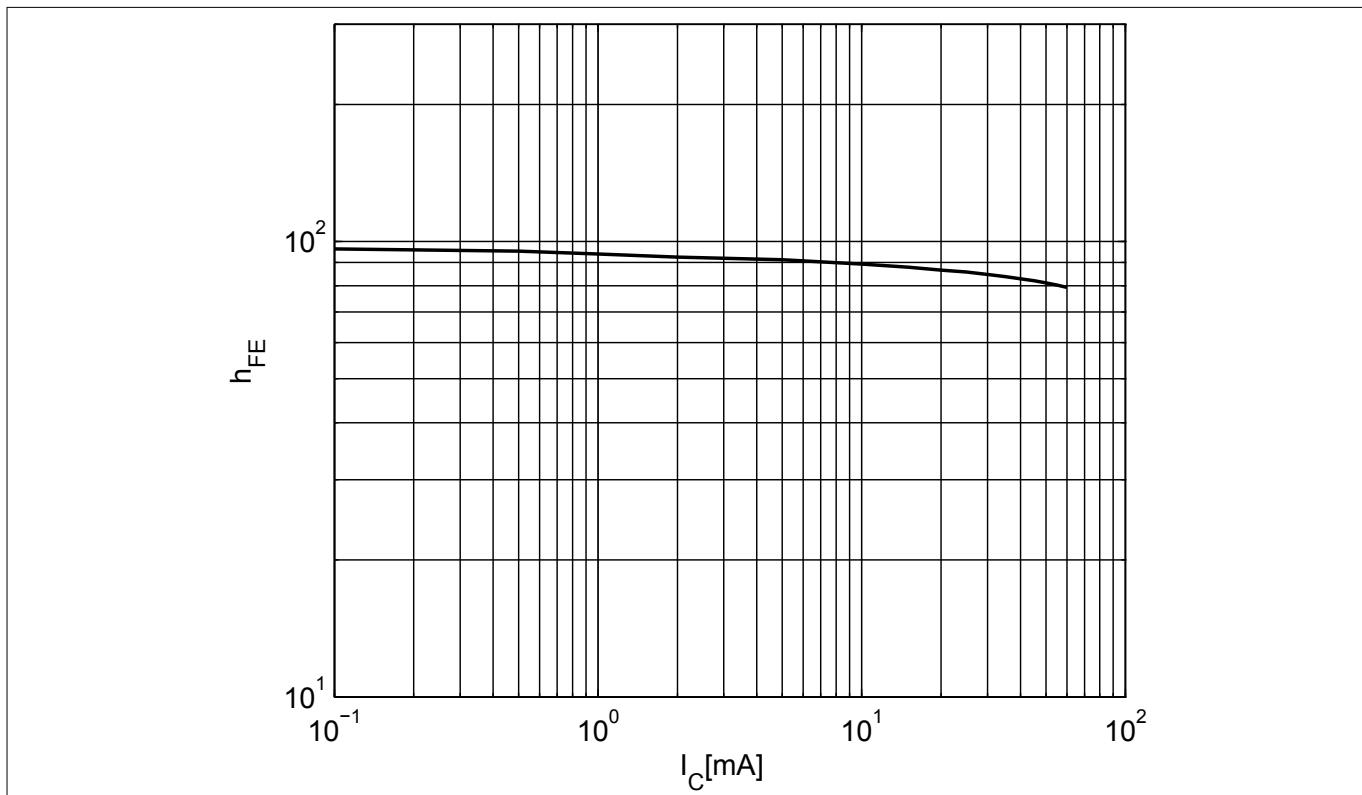
Figure 3 Collector current vs. collector emitter voltage $I_C = f(V_{CE})$, I_B = parameter

Figure 4

DC current gain $h_{FE} = f(I_C)$, $V_{CE} = 3$ V

Electrical characteristics

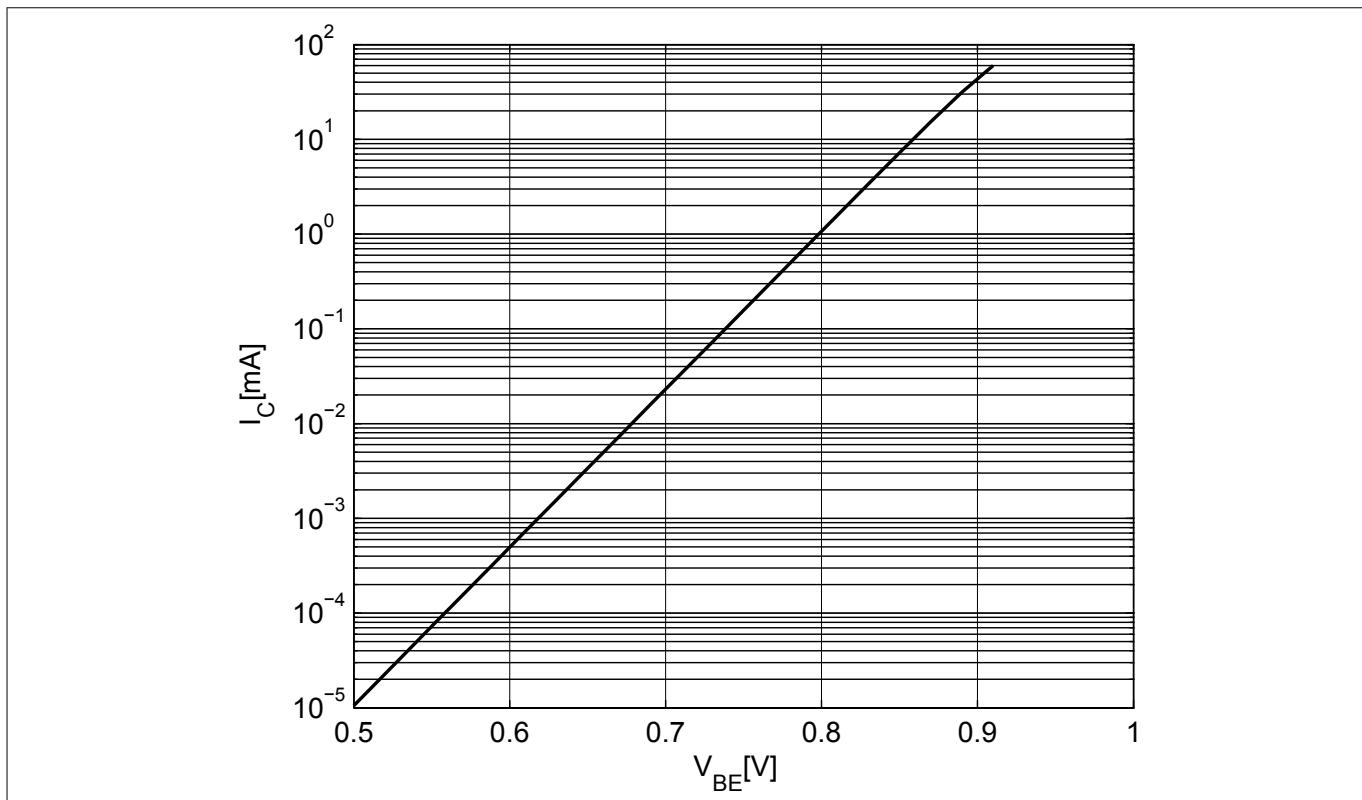


Figure 5 Collector current vs. base emitter forward voltage $I_C = f(V_{BE})$, $V_{CE} = 3$ V

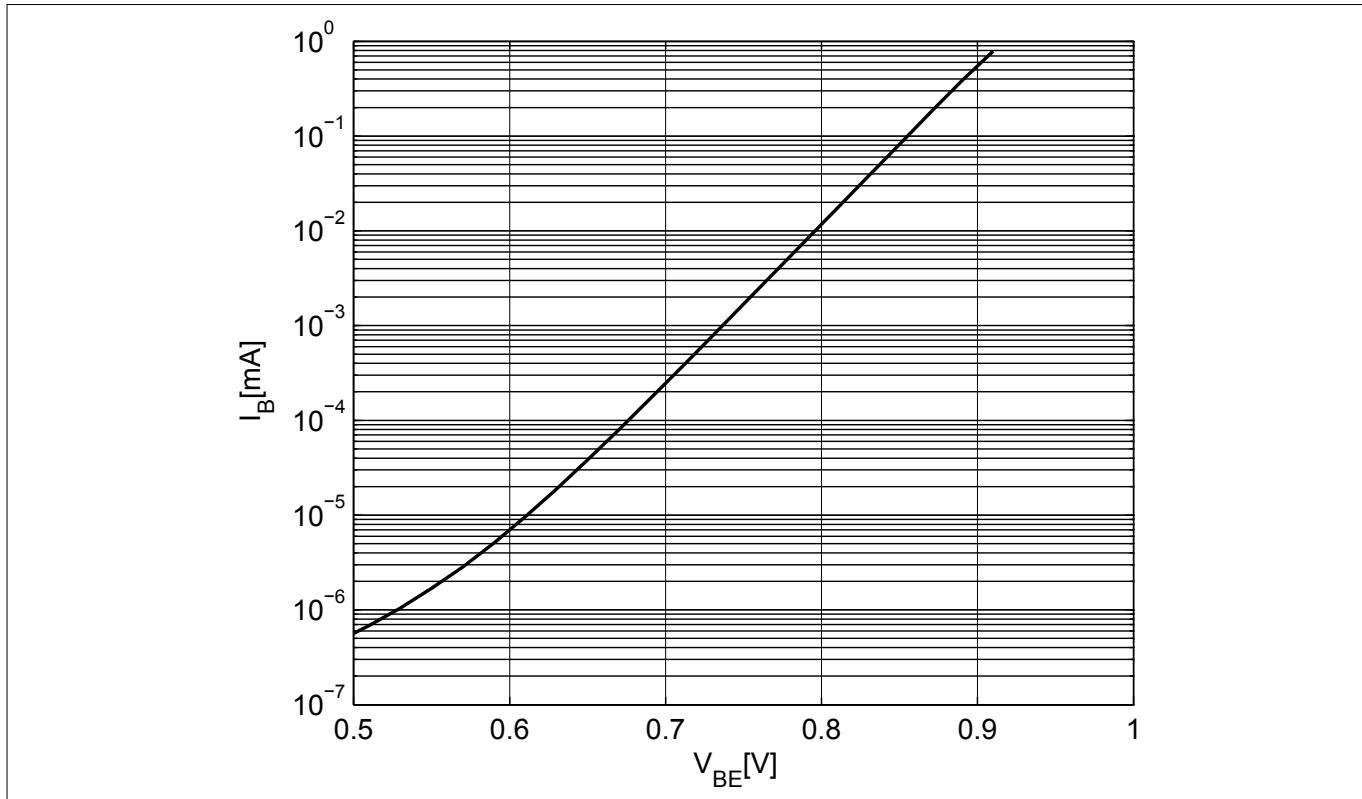


Figure 6 Base current vs. base emitter forward voltage $I_B = f(V_{BE})$, $V_{CE} = 3$ V

Electrical characteristics

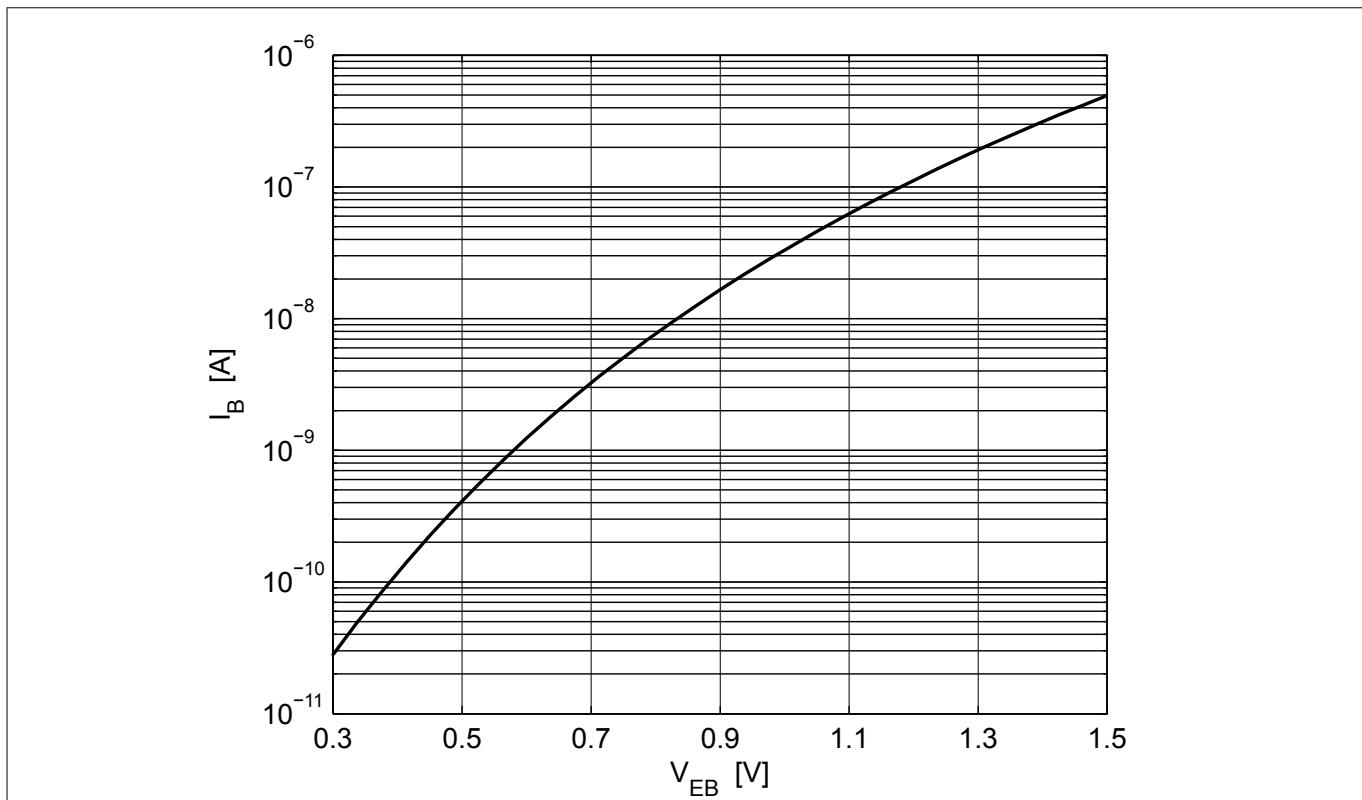


Figure 7 Base current vs. base emitter reverse voltage $I_B = f(V_{EB})$, $V_{CE} = 3$ V

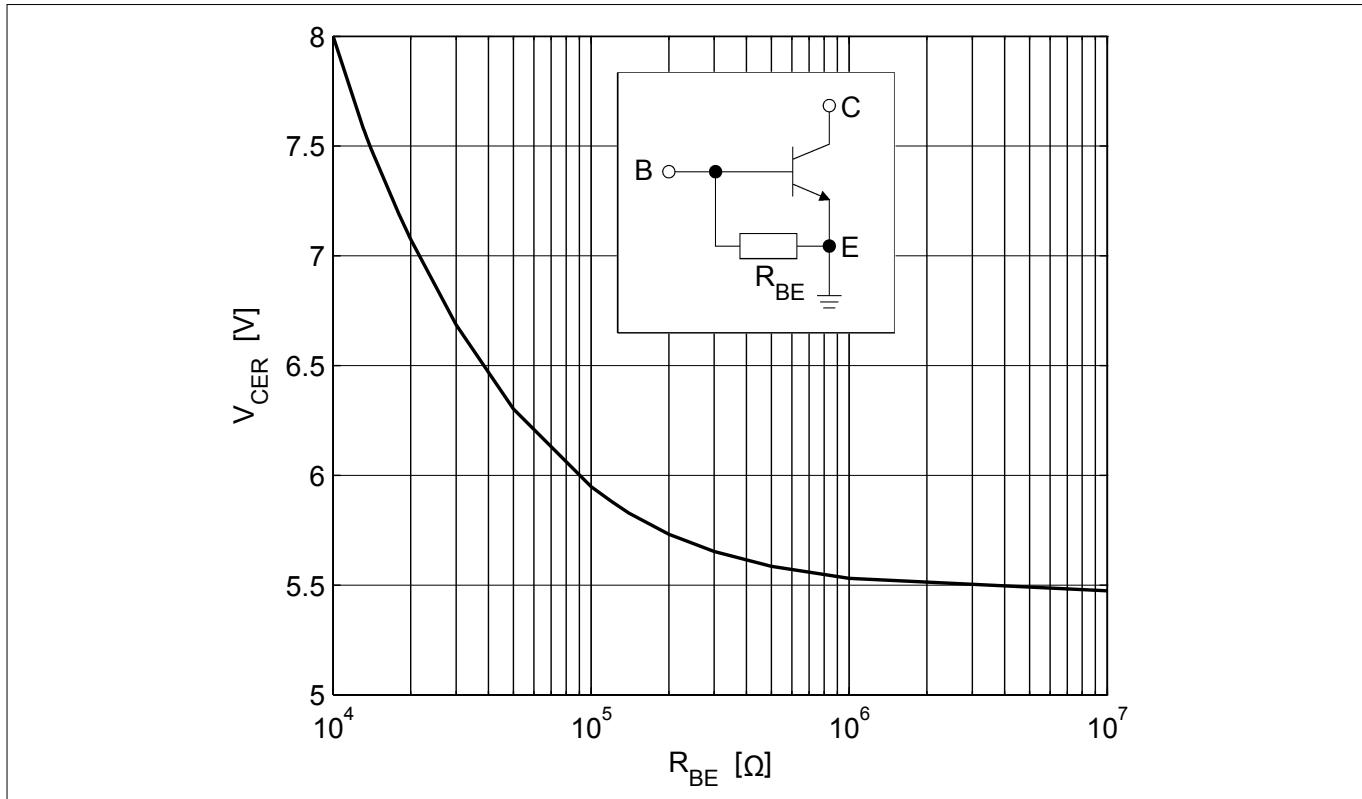


Figure 8 Collector emitter breakdown voltage $V_{CER} = f(R_{BE})$, $I_C = 1$ mA

Electrical characteristics

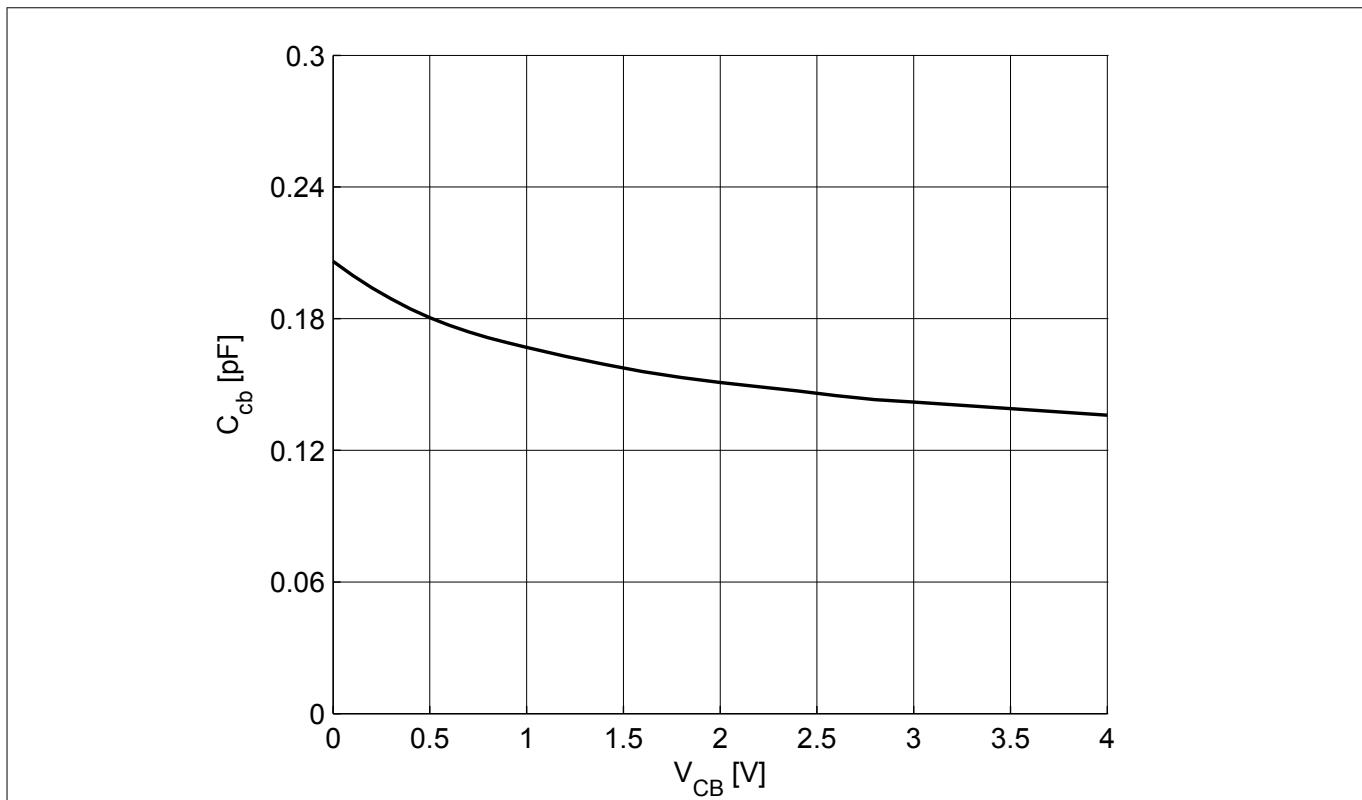


Figure 13 Collector base capacitance $C_{CB} = f(V_{CB})$, $f = 1$ MHz

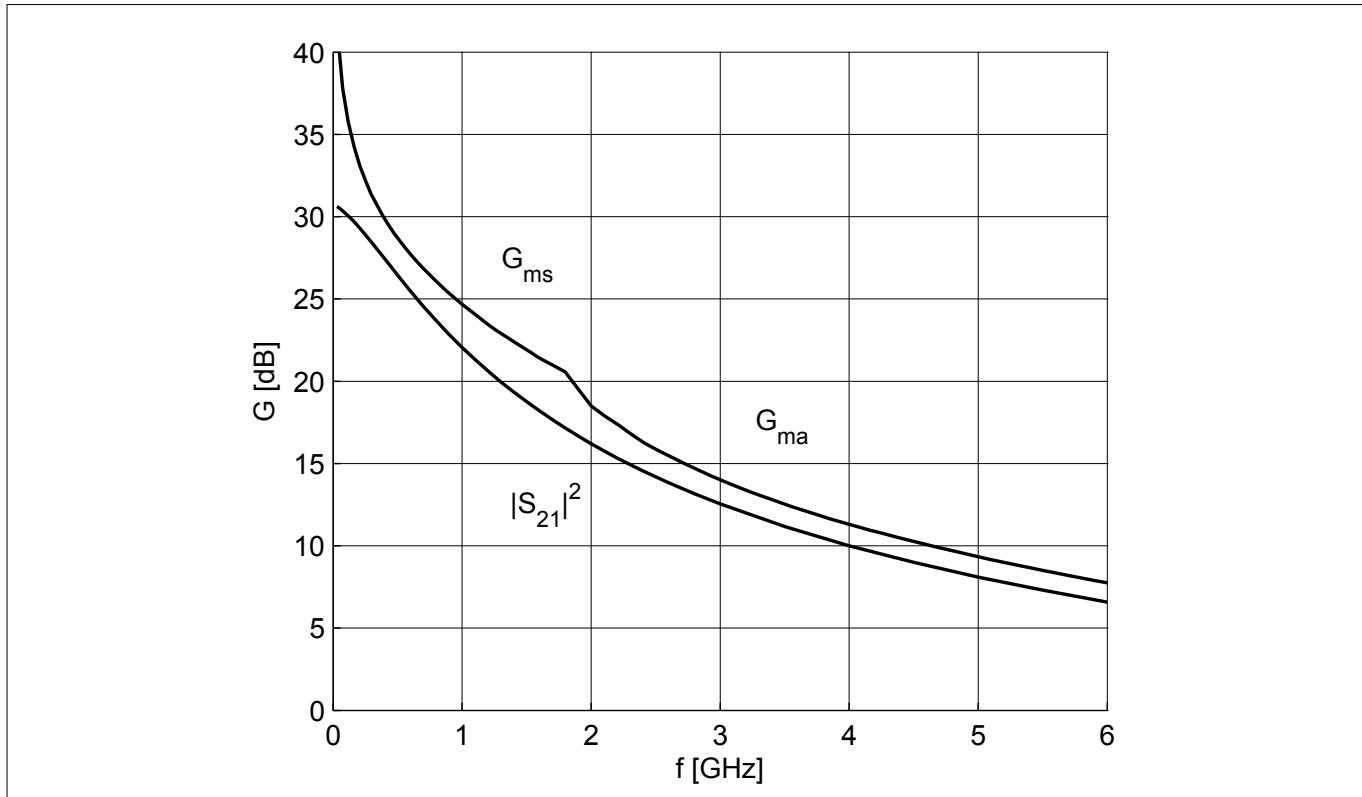


Figure 14 Gain G_{ma} , G_{ms} , $|S_{21}|^2 = f(f)$, $V_{CE} = 3$ V, $I_C = 15$ mA

Electrical characteristics

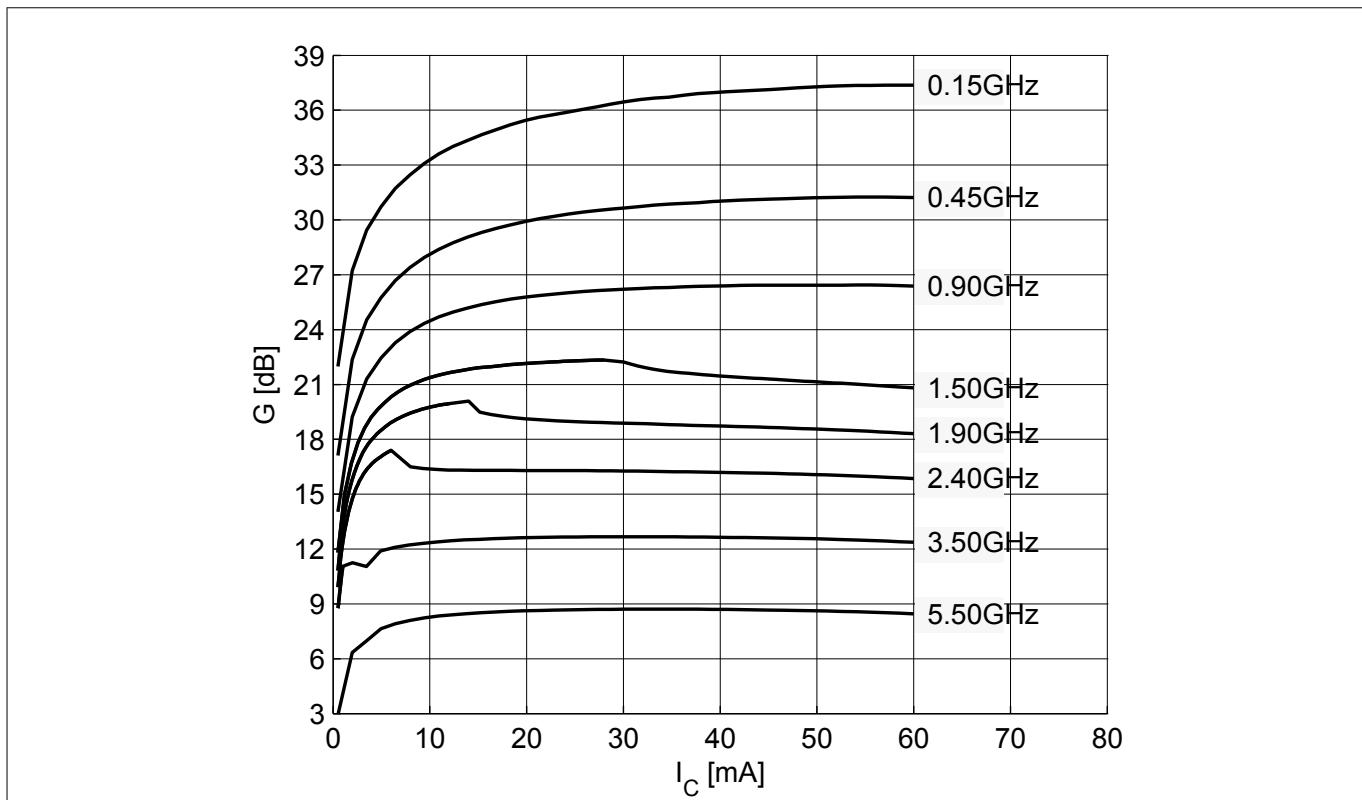


Figure 15 Maximum power gain $G_{\max} = f(I_C)$, $V_{CE} = 3$ V, f = parameter in GHz

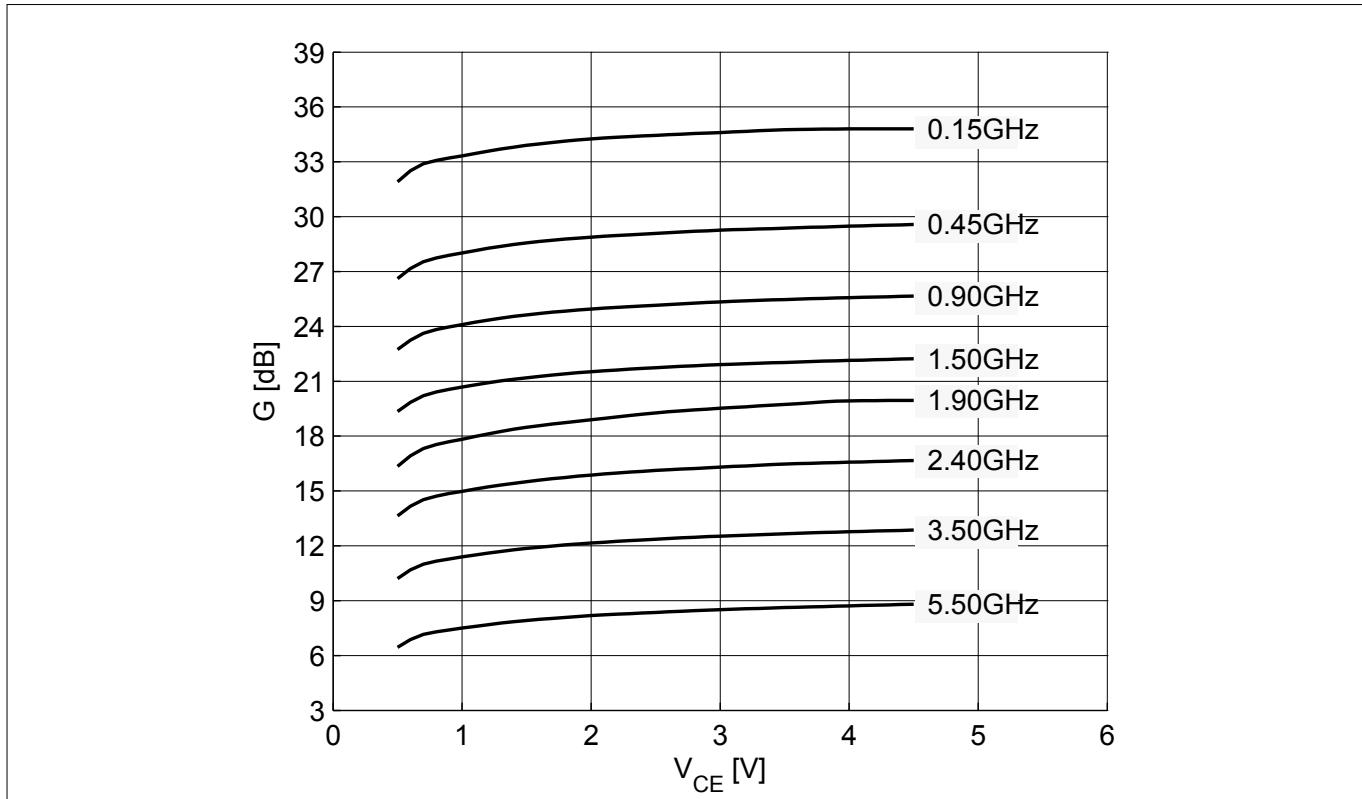


Figure 16 Maximum power gain $G_{\max} = f(V_{CE})$, $I_C = 15$ mA, f = parameter in GHz

Electrical characteristics

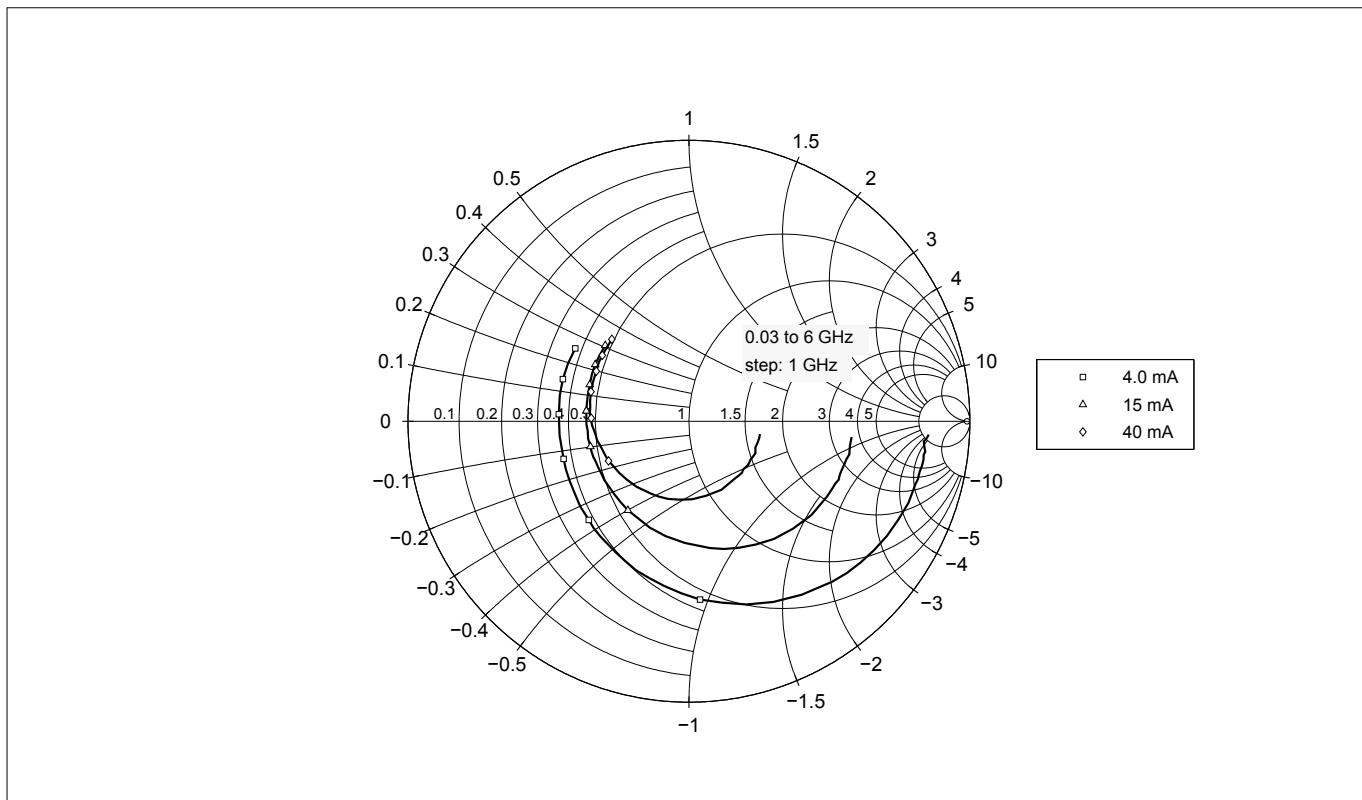


Figure 17 **Input reflection coefficient $S_{11} = f(f)$, $V_{CE} = 3 \text{ V}$, $I_C = 4 / 15 / 40 \text{ mA}$**

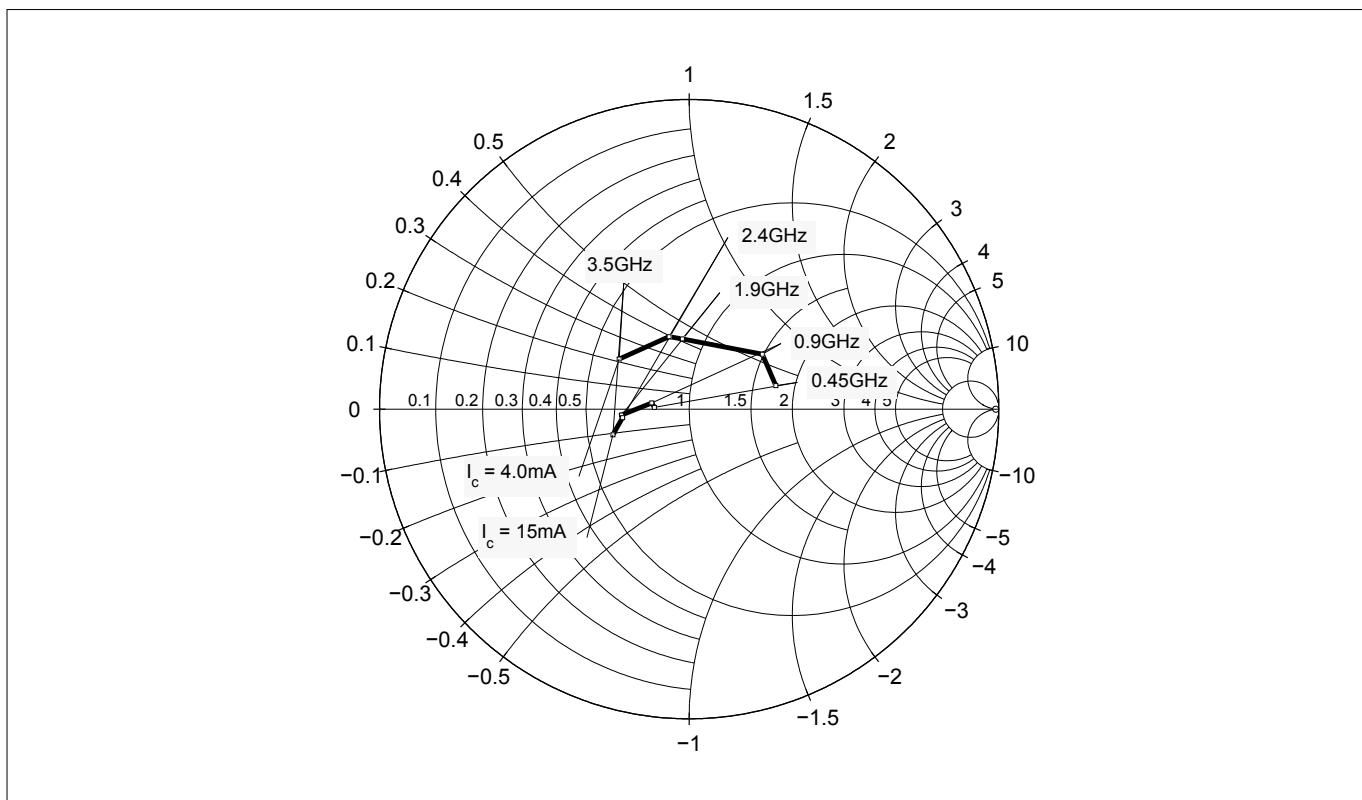


Figure 18 **Source impedance for minimum noise figure $Z_{S,\text{opt}} = f(f)$, $V_{CE} = 3 \text{ V}$, $I_C = 4 / 15 \text{ mA}$**

Electrical characteristics

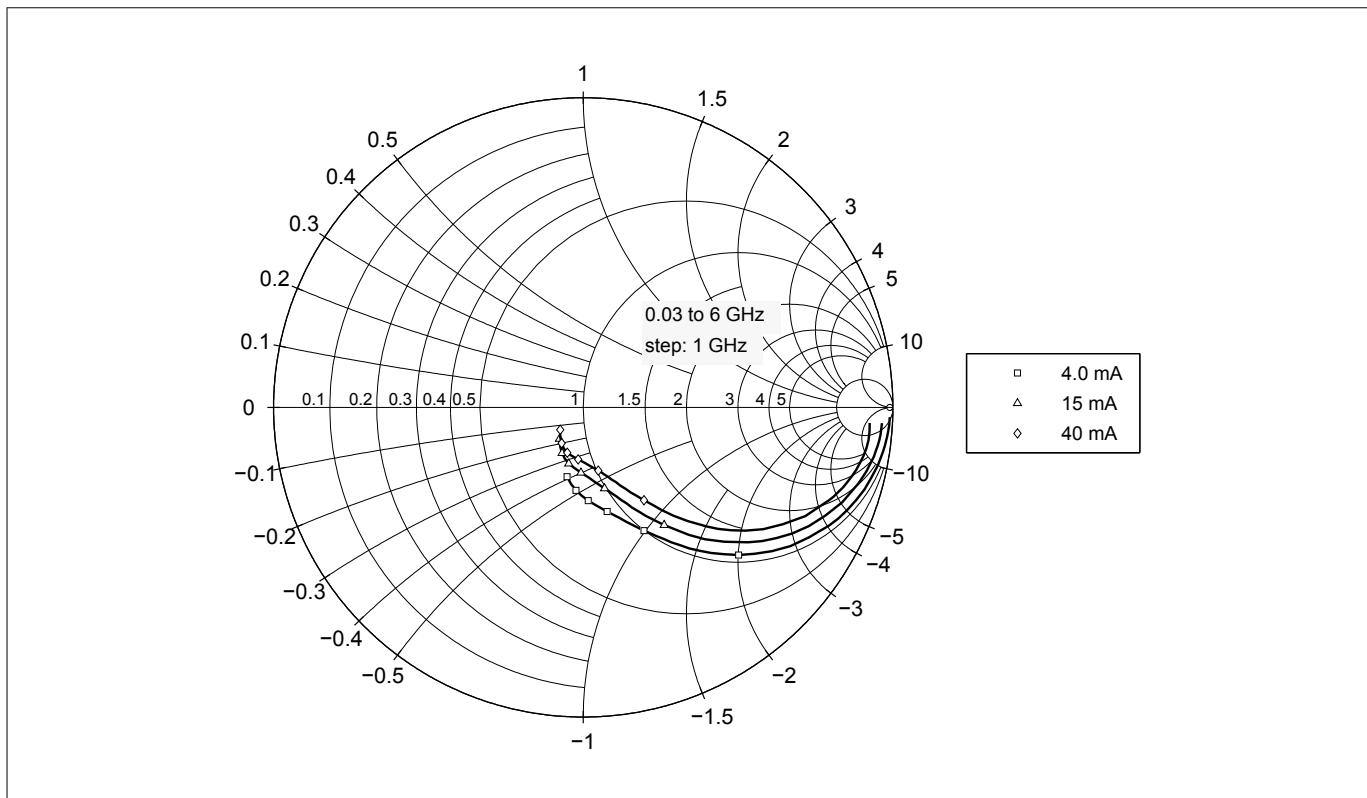


Figure 19 Output reflection coefficient $S_{22} = f(f)$, $V_{CE} = 3 \text{ V}$, $I_C = 4 / 15 / 40 \text{ mA}$

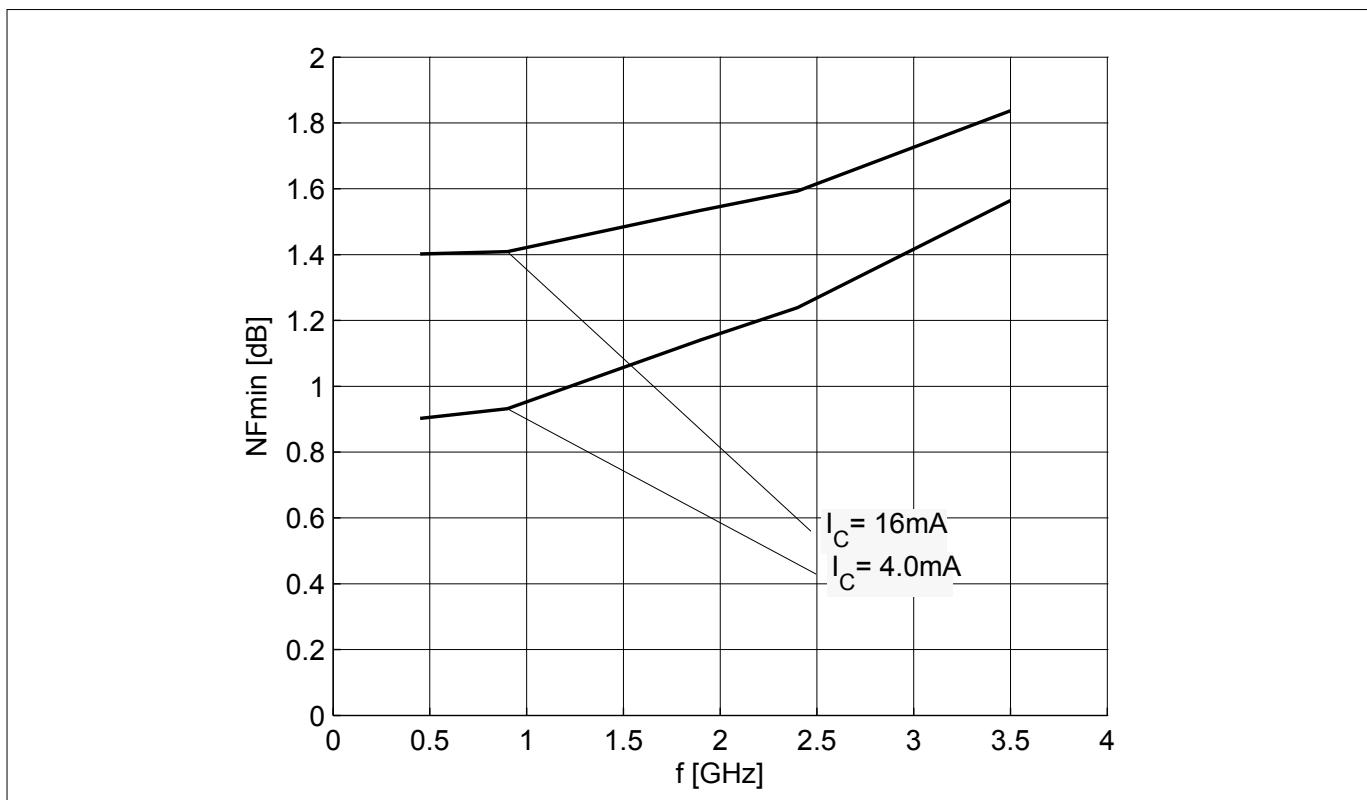


Figure 20 Noise figure $NF_{\min} = f(f)$, $V_{CE} = 3 \text{ V}$, $Z_S = Z_{S,\text{opt}}$, $I_C = 4 / 16 \text{ mA}$

Package information TSFP-4-1

4 Package information TSFP-4-1

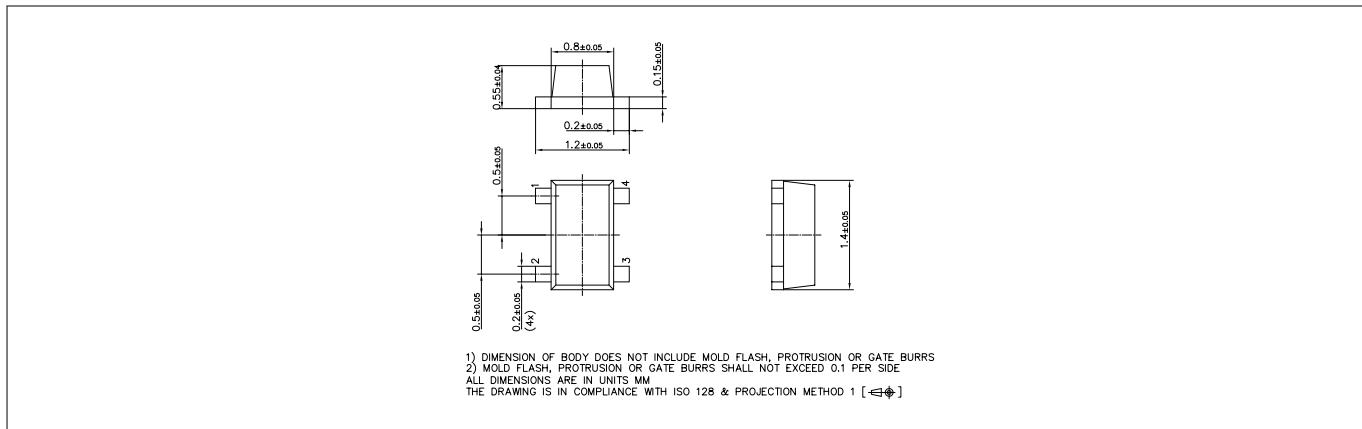


Figure 23 Package outline

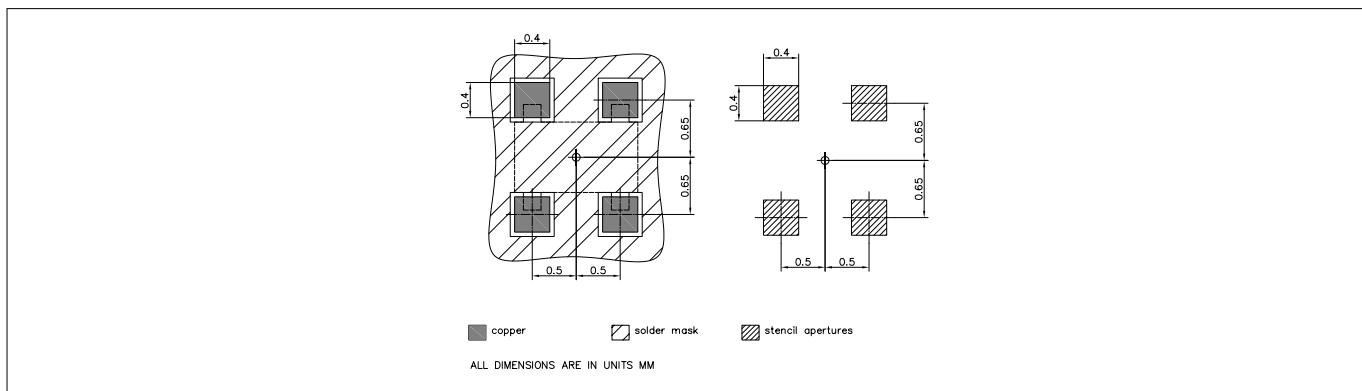


Figure 24 Foot print

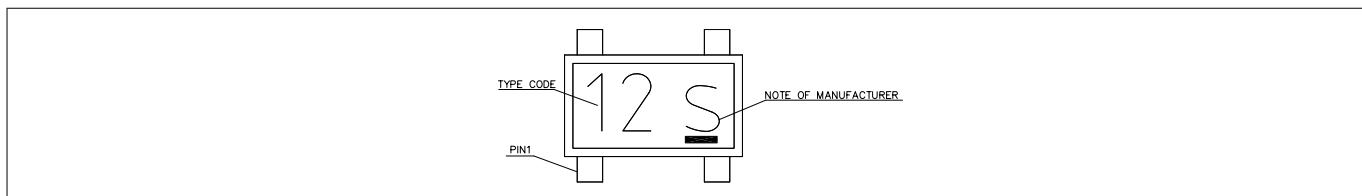


Figure 25 Marking layout example

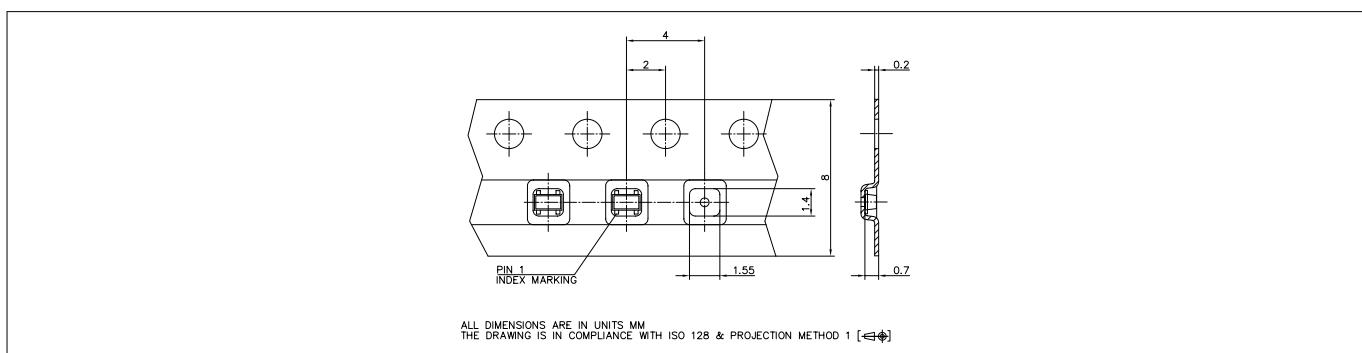


Figure 26 Tape dimensions

Revision history

Revision history

Document version	Date of release	Description of changes
Revision 2.0	2019-01-25	New datasheet layout.

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